

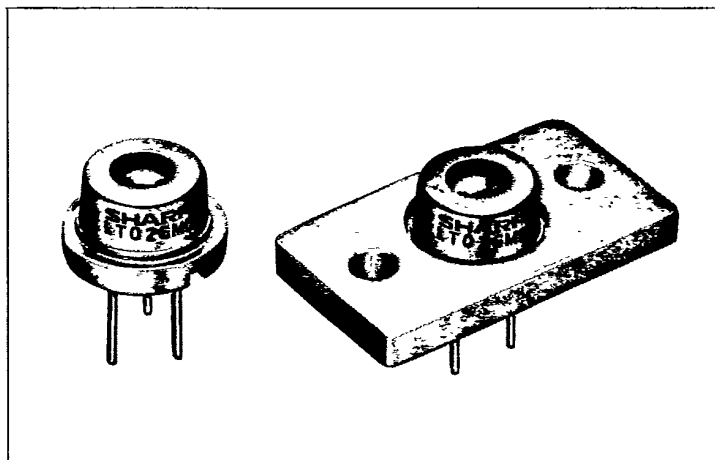
LT026MD/MF

Features

- Small astigmatic distance (less than 10 μm)
- Wavelength: 780nm
- Single transverse mode

Applications

- General purpose laser printers
- Information processing equipment



Absolute Maximum Ratings

(T_c=25°C)

Parameter	Symbol	Ratings	Units
Optical power output	P _o	5	mW
Reverse voltage	V _R	2	V
		30	
Operating temperature *1	T _{opr}	-10 ~ +60	°C
Storage temperature *1	T _{stg}	-40 ~ +85	°C
Soldering temperature *2	T _{sol}	260 (less than 5 seconds)	°C

*1 Case temperature *2 At point 1.6 mm from lead base

Electro-optical Characteristics *1

(T_c=25°C)

Parameter			Symbol	Condition	Ratings			Units
					MIN	TYP	MAX	
Threshold current			I _{th}	—	—	50	80	mA
Operating current			I _{op}	P _o =3mW	—	65	100	mA
Operating voltage			V _{op}	P _o =3mW	—	1.75	2.2	V
Wavelength *2			λ _p	P _o =3mW	770	780	790	nm
Monitor current			I _m	P _o =3mW V _R =15V	0.3	0.9	1.6	mA
Radiation characteristics	Angle *3	Parallel to junction	θ ∥	P _o =3mW	8	11	16	deg
		Perpendicular to junction	θ ⊥	P _o =3mW	20	29	36	deg
	Ripple			P _o =3mW	—	—	±20	%
Emission point accuracy	Angle		Δφ ∥	P _o =3mW	—	—	±2	deg
			Δφ ⊥	P _o =3mW	—	—	±3	deg
	Position *4		Δx, Δy, Δz	—	—	—	±80	μm
Differential efficiency			η	$\frac{2\text{mW}}{I_F(3\text{mW}) - I_F(1\text{mW})}$	0.2	0.3	0.5	mW/mA

*1 Initial value

*3 Angle at 50% peak intensity (full width at half-maximum)

*2 Single transverse mode

*4 Not specified for LT026MF

Electrical Characteristics of Photodiode

(T_c=25°C)

Parameter	Symbol	Condition	Ratings			Units
			MIN	TYP	MAX	
Sensitivity	S	V _R =15V	—	0.3	—	mA/mW
Dark current	I _o	V _R =15V	—	—	250	nA
Terminal capacitance	C _t	V _R =15V	—	8	20	pF